

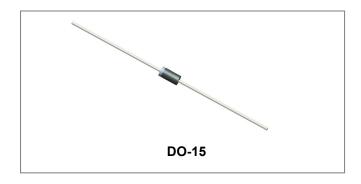
Data Sheet N1630, Rev. A

Technical Data

RL251G-RL257G

RoHS 🗭

RL251G THRU RL257G GENERAL PURPOSE PLASTIC RECTIFIER



Features

- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Solder Resistance 270°C / 7s, or 380°C / 3s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014 ounce, 0.40 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	RL 251G	RL 252G	RL 253G	RL 254G	RL 255G	RL 256G	RL 257G	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	V _{RRM} V _{DC}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum average forward rectified current $0.375"(9.5mm)$ lead length $@T_A = 75^{\circ}C$	I _(AV)	2.5					А		
Peak forward surge current 8.3ms single half sine- wave superimposed on rated load (JEDEC Method)	IFSM	120				А			
Maximum instantaneous forward voltage at 2.5A	VF	1.1				V			
Maximum DC reverse current $@T_A = 25^{\circ}C$ at rated DC blocking voltage $@T_A = 100^{\circ}C$	I _R	2.5 50.0				μA			
Typical Junction Capacitance (Note 1)	CJ	45.0			pF				
Typical Thermal Resistance (Note 2)	Reja	45.0				°C/W			
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150				°C			

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •

Circuit Diagram



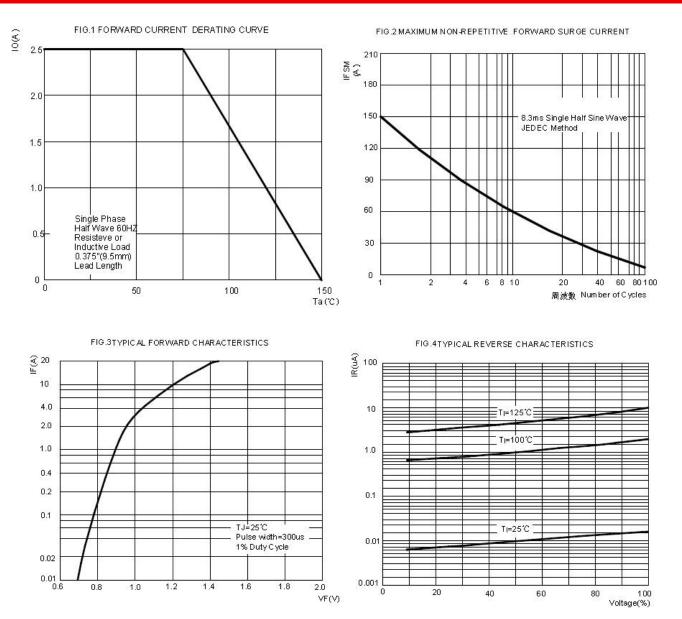


RL251G-RL257G

Technical Data Data Sheet N1630, Rev. A

RoHS 🗭

Ratings and Characteristics Curves



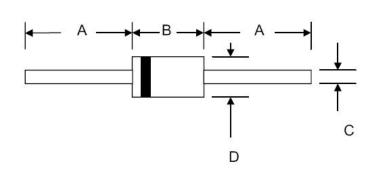


RL251G-RL257G

Technical Data Data Sheet N1630, Rev. A



Mechanical Dimensions DO-15



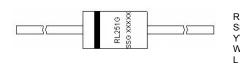
SYMBOL	Millin	neters	Inches			
	Min. Max.		Min.	Max.		
A	25.4	-	1.000	-		
В	5.5	7.62	0.217	0.300		
С	0.7	0.9	0.028	0.034		
D	2.6	3.6	0.104	0.140		

Ordering Information

Device	Package	Shipping		
RL251G-RL257G	DO-15 (Pb-Free)	3000pcs /tape		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

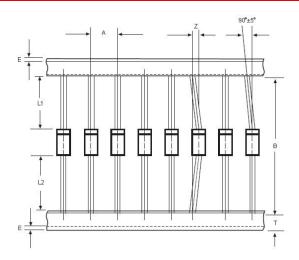


Where XXXXX is YYWWL

- RL251G = Type Number SSG YY
 - = SSG
 - = Year = Week
- WW = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-15



SYMBOL	Millimeters			
	Min.	Max.		
A	4.50	5.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

• China - Germany - Korea - Singapore - United States • • http://www.smc-diodes.com - sales@ smc-diodes.com •



Technical Data Data Sheet N1630, Rev. A





DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.

http://www.smc-diodes.com - sales@ smc-diodes.com •

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by SMC Diode manufacturer:

Other Similar products are found below :

MMBD3004S-13-F RD0306T-H DSE010-TR-E BAV17-TR BAV19-TR 1N3611 NTE156A NTE574 NTE6244 1SS181-TP 1SS193,LF 1SS400CST2RA SDAA13 SHN2D02FUTW1T1G LS4151GS08 FC903-TR-E 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR 1SS226-TP RFUH20TB3S D291S45T BAV300-TR BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18 053684A SMMSD4148T3G 707803H NSVDAN222T1G CDSZC01100-HF LL4150-M-08 BAV199E6433HTMA1 BAS28-7 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3 NSVM1MA152WKT1G RGP30D-E3/73 BAV99TQ-13-F BAS21DWA-7 NTE6250 NTE582-4 NTE582-6 MMDB30-E28X